

General Description

The SN74HC/HCT112 is a dual negative-edge triggered JK flip-flop.

Features

- Supply voltage range:
SN74HC112: 2~6V
SN74HCT112: 4.5~5.5V
- Input levels:
SN74HC112: CMOS level
SN74HCT112: TTL level
- Temperature range:-40°C to +125°C
- Packaging information: DIP16/SOP16/TSSOP16

Ordering Information

Product Model	Package Type	Marking	Packing	Packing Qty
XBLW SN74HC112N	DIP-16	74HC112N	Tube	1000Pcs/Box
XBLW SN74HC112DTR	SOP-16	74HC112	Tape	2500Pcs/Reel
XBLW SN74HC112TDTR	TSSOP-16	74HC112	Tape	3000Pcs/Reel
XBLW SN74HCT112N	DIP-16	74HCT112N	Tube	1000Pcs/Box
XBLW SN74HCT112DTR	SOP-16	74HCT112	Tape	2500Pcs/Reel
XBLW SN74HCT112TDTR	TSSOP-16	74HCT112	Tape	3000Pcs/Reel

Block Diagram And Pin Description

Block Diagram

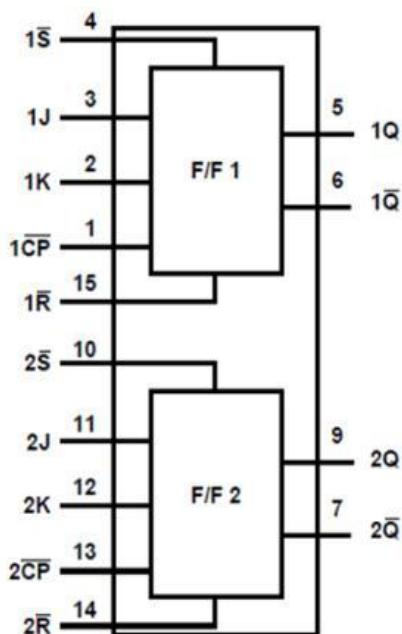
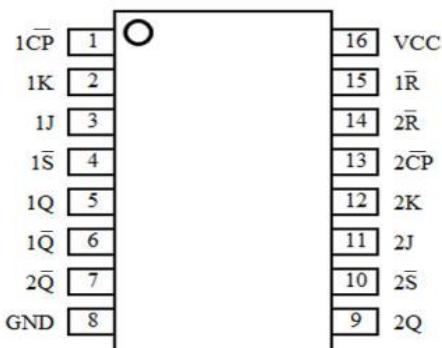


Figure 1. Functional diagram

Pin Configurations



Pin Description

Pin No.	Pin Name	Description
1	1CP-	clock input (HIGH-to-LOW; edge-triggered)
2	1K	data input
3	1J	data input
4	1S-	set input (active LOW)
5	1Q	true flip-flop output
6	1Q-	complement flip-flop output
7	2Q-	complement flip-flop output
8	GND	ground (0V)
9	2Q	true flip-flop output
10	2S-	set input (active LOW)
11	2J	data input
12	2K	data input
13	2CP-	clock input (HIGH-to-LOW; edge-triggered)
14	2R-	reset input (active LOW)
15	1R-	reset input (active LOW)
16	VCC	supply voltage

Function Table

Inputs					Outputs	
S-	R-	CP-	J	K	Q	Q-
L	H	X	X	X	H	L
H	L	X	X	X	L	H
L	L	X	X	X	H(Note 1)	H(Note 1)
H	H	↓	L	L	No Change	
H	H	↓	H	L	H	L
H	H	↓	L	H	L	H
H	H	↓	H	H	Toggle	
H	H	H	X	X	No Change	

H= High Level (Steady State)

L= Low Level (Steady State)

X= Don't Care

↓ = High-to-Low Transition

NOTE 1: Output states unpredictable if both S and R go High simultaneously after both being low at the sametime



Electrical Parameter

Absolute Maximum Ratings

($T_{amb}=25^{\circ}C$, All voltage referenced to Vss, unless otherwise specified)

Parameter	Symbol	Conditions		Min.	Max.	Unit
supply voltage	V_{CC}	-		-0.5	+7	V
ground current	I_{GND}	-		-50	-	mA
input clamping current	I_{IK}	$V_I < -0.5V$ or $V_I > V_{CC}+0.5V$		-	± 20	mA
output clamping current	I_{OK}	$V_O < -0.5V$ or $V_O > V_{CC}+0.5V$		-	± 20	mA
output current	I_O	$-0.5V < V_O < V_{CC}+0.5V$		-	± 25	mA
storage temperature	T_{stg}	-		-65	+150	°C
soldering temperature	T_L	10s	DIP SOP/TSSOP	245 260		°C

Electrical Characteristics

DC Characteristics 1

($T_{amb}=-40^{\circ}C$ to $+85^{\circ}C$, voltages are referenced to V_{SS} (ground=0V), unless otherwise specified.)

Parameter	Symbol	V_{CC}	Conditions	Min.	Typ.	Max.	Unit
SN74HC112							
HIGH-level input voltage	V_{IH}	2.0V	-	1.5	1.2	-	V
		4.5V	-	3.15	2.4	-	V
		6.0V	-	4.2	3.2	-	V
LOW-level input voltage	V_{IL}	2.0V	-	-	0.8	0.5	V
		4.5V	-	-	2.1	1.35	V
		6.0V	-	-	2.8	1.8	V
HIGH-level output voltage	V_{OH}	2.0V	$I_O=-20\mu A$	1.9	2.0	-	V
		4.5V	$I_O=-20\mu A$	4.4	4.5	-	V
		6.0V	$I_O=-20\mu A$	5.9	6.0	-	V
		4.5V	$I_O=-4.0mA$	3.84	4.32	-	V
		6.0V	$I_O=-5.2mA$	5.34	5.81	-	V
LOW-level output voltage	V_{OL}	2.0V	$I_O=20\mu A$	-	0	0.1	V
		4.5V	$I_O=20\mu A$	-	0	0.1	V
		6.0V	$I_O=20\mu A$	-	0	0.1	V
		4.5V	$I_O=4.0mA$	-	0.15	0.33	V
		6.0V	$I_O=5.2mA$	-	0.16	0.33	V
input leakage current	I_I	6.0V	$V_I=V_{CC}$ or GND	-	-	± 1	μA
supply current	I_{CC}	6.0V	$V_I=V_{CC}$ or GND; $I_O=0A$	-	-	80	μA
SN74HCT112							
HIGH-level input voltage	V_{IH}	4.5~5.5V	-	2.0	1.6	-	V
LOW-level input voltage	V_{IL}	4.5~5.5V	-	-	1.2	0.8	V
HIGH-level output voltage	V_{OH}	4.5V	$I_O=-20\mu A$	4.4	4.5	-	V
			$I_O=-4.0mA$	3.84	4.32	-	V



LOW-level output voltage	V _{OL}	4.5V	I _O =20uA I _O =4.0mA	-	0	0.1	V
input leakage current	I _I	5.5V	V _I =V _{CC} or GND	-	0.15	0.33	V
supply current	I _{CC}	6.0V	V _I =V _{CC} or GND; I _O =0A	-	-	80	uA
additional supply current	ΔI _{CC}	4.5~5.5V	One input at V _I =V _{CC} -2.1V; Other inputs at V _{CC} or GND; I _O =0A	-	-	135	uA

DC Characteristics 2

(T_{amb}=-40°C to +125°C, voltages are referenced to V_{SS} (ground=0V), unless otherwise specified.)

Parameter	Symbol	V _{CC}	Conditions	Min.	Typ.	Max.	Unit
SN74HC112							
HIGH-level input voltage	V _{IH}	2.0V	-	1.5	-	-	V
		4.5V	-	3.15	-	-	V
		6.0V	-	4.2	-	-	V
LOW-level input voltage	V _{IL}	2.0V	-	-	-	0.5	V
		4.5V	-	-	-	1.35	V
		6.0V	-	-	-	1.8	V
HIGH-level output voltage	V _{OH}	2.0V	I _O =-20uA	1.9	-	-	V
		4.5V	I _O =-20uA	4.4	-	-	V
		6.0V	I _O =-20uA	5.9	-	-	V
		4.5V	I _O =-4.0mA	3.7	-	-	V
		6.0V	I _O =-5.2mA	5.2	-	-	V
LOW-level output voltage	V _{OL}	2.0V	I _O =20uA	-	-	0.1	V
		4.5V	I _O =20uA	-	-	0.1	V
		6.0V	I _O =20uA	-	-	0.1	V
		4.5V	I _O =4.0mA	-	-	0.4	V
		6.0V	I _O =5.2mA	-	-	0.4	V
input leakage current	I _I	6.0V	V _I =V _{CC} or GND	-	-	±1	uA
supply current	I _{CC}	6.0V	V _I =V _{CC} or GND; I _O =0A	-	-	160	uA
SN74HCT112							
HIGH-level input voltage	V _{IH}	4.5~5.5V	-	2.0	-	-	V
LOW-level input voltage	V _{IL}	4.5~5.5V	-	-	-	0.8	V
HIGH-level output voltage	V _{OH}	4.5V	I _O =-20uA	4.4	-	-	V
			I _O =-4.0mA	3.7	-	-	V
LOW-level output voltage	V _{OL}	4.5V	I _O =20uA	-	-	0.1	V
			I _O =4.0mA	-	-	0.4	V
input leakage current	I _I	5.5V	V _I =V _{CC} or GND	-	-	±1	uA
supply current	I _{CC}	6.0V	V _I =V _{CC} or GND; I _O =0A	-	-	160	uA
additional supply current	ΔI _{CC}	4.5~5.5V	One input at V _I =V _{CC} -2.1V; Other inputs at V _{CC} or GND; I _O =0A	-	-	147	uA



AC Characteristics 1

($T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{ss}=0\text{V}$, unless otherwise specified.)

Parameter	Symbol	V _{cc}	Conditions	Min.	Typ.	Max.	Unit	
SN74HC112								
nCP tonQ propagation delay		2.0V	$C_L=50\text{pF}$	see Figure 5	-	55	220	ns
		4.5V	$C_L=50\text{pF}$		-	20	44	ns
		5.0V	$C_L=15\text{pF}$		-	17	-	ns
		6.0V	$C_L=50\text{pF}$		-	16	37	ns
nCP tonQ _— propagation delay		2.0V	$C_L=50\text{pF}$	see Figure 5	-	55	220	ns
		4.5V	$C_L=50\text{pF}$		-	20	44	ns
		5.0V	$C_L=15\text{pF}$		-	17	-	ns
		6.0V	$C_L=50\text{pF}$		-	16	37	ns
nR tonQ _— 、 nQ propagation delay		2.0V	$C_L=50\text{pF}$	see Figure 6	-	58	225	ns
		4.5V	$C_L=50\text{pF}$		-	21	45	ns
		5.0V	$C_L=15\text{pF}$		-	18	-	ns
		6.0V	$C_L=50\text{pF}$		-	17	38	ns
nS tonQ _— 、 nQ propagation delay		2.0V	$C_L=50\text{pF}$	see Figure 6	-	50	295	ns
		4.5V	$C_L=50\text{pF}$		-	18	39	ns
		5.0V	$C_L=15\text{pF}$		-	15	-	ns
		6.0V	$C_L=50\text{pF}$		-	14	33	ns
transition time		2.0V	$C_L=50\text{pF}$	see Figure 5	-	19	95	ns
		4.5V	$C_L=50\text{pF}$		-	7	19	ns
		6.0V	$C_L=50\text{pF}$		-	6	16	ns
nCP _— HIGH or LOW pulse width		2.0V	$C_L=50\text{pF}$	see Figure 5	100	22	-	ns
		4.5V	$C_L=50\text{pF}$		20	8	-	ns
		6.0V	$C_L=50\text{pF}$		17	6	-	ns
nS,nR _— LOW pulse width		2.0V	$C_L=50\text{pF}$	see Figure 6	100	22	-	ns
		4.5V	$C_L=50\text{pF}$		20	8	-	ns
		6.0V	$C_L=50\text{pF}$		17	6	-	ns
nR tonCP recovery time		2.0V	$C_L=50\text{pF}$	see Figure 6	125	22	-	ns
		4.5V	$C_L=50\text{pF}$		25	8	-	ns
		6.0V	$C_L=50\text{pF}$		21	6	-	ns
nS tonCP recovery time		2.0V	$C_L=50\text{pF}$	see Figure 6	100	-19	-	ns
		4.5V	$C_L=50\text{pF}$		20	-7	-	ns
		6.0V	$C_L=50\text{pF}$		17	-6	-	ns
nJ and nK ton CP set-up time		2.0V	$C_L=50\text{pF}$	see Figure 5	100	19	-	ns
		4.5V	$C_L=50\text{pF}$		20	7	-	ns
		6.0V	$C_L=50\text{pF}$		17	6	-	ns
nJ and nK ton CP hold time		2.0V	$C_L=50\text{pF}$	see Figure 5	0	-11	-	ns
		4.5V	$C_L=50\text{pF}$		0	-4	-	ns
		6.0V	$C_L=50\text{pF}$		0	-3	-	ns
maximum frequency		2.0V	$C_L=50\text{pF}$	see Figure 5	4.8	20	-	MHz
		4.5V	$C_L=50\text{pF}$		24	60	-	MHz
		5.0V	$C_L=15\text{pF}$		-	66	-	MHz



		6.0V	$C_L=50\text{pF}$		28	71	-	MHz
SN74HCT112								
nCP ⁻ tonQ propagation delay		4.5V	$C_L=50\text{pF}$	see Figure 5	-	21	44	ns
		5.0V	$C_L=15\text{pF}$		-	19	-	ns
nCP ⁻ tonQ ⁻ propagation delay		4.5V	$C_L=50\text{pF}$	see Figure 5	-	23	50	ns
		5.0V	$C_L=15\text{pF}$		-	19	-	ns
nR ⁻ tonQ ⁻ 、nQ propagation delay		4.5V	$C_L=50\text{pF}$	see Figure 6	-	22	46	ns
		5.0V	$C_L=15\text{pF}$		-	19	-	ns
nS ⁻ tonQ ⁻ 、nQ propagation delay		4.5V	$C_L=50\text{pF}$	see Figure 6	-	18	40	ns
		5.0V	$C_L=15\text{pF}$		-	15	-	ns
transition time	t _{THL} , t _{T LH}	4.5V	$C_L=50\text{pF}$	see Figure 5	-	7	19	ns
nCP ⁻ HIGH or LOW pulse width	tw	4.5V	$C_L=50\text{pF}$	see Figure 5	20	8	-	ns
nS, nR ⁻ LOW pulse width		4.5V	$C_L=50\text{pF}$	see Figure 6	23	10	-	ns
nR ⁻ tonCP ⁻ recovery time	t _{REC}	4.5V	$C_L=50\text{pF}$	see Figure 6	25	11	-	ns
nS tonCP ⁻ recovery time		4.5V	$C_L=50\text{pF}$	see Figure 6	25	-8	-	ns
nJ and nK ton CP set-up time	tsu	4.5V	$C_L=50\text{pF}$	see Figure 5	20	7	-	ns
nJ and nK ton CP hold time	th	4.5V	$C_L=50\text{pF}$	see Figure 5	0	-7	-	ns
maximum frequency	f _{max}	4.5V	$C_L=50\text{pF}$	see Figure 5	24	64	-	MHz
		5.0V	$C_L=15\text{pF}$		-	70	-	MHz

AC Characteristics 2

(T_{amb}=-40°C to +125°C, V_{SS}=0V, unless otherwise specified.)

Parameter	Symbol	V _{CC}	Conditions	Min.	Typ.	Max.	Unit	
SN74HC112								
nCP ⁻ tonQ propagation delay		2.0V	$C_L=50\text{pF}$	see Figure 3	-	-	265	ns
		4.5V	$C_L=50\text{pF}$		-	-	53	ns
nCP ⁻ tonQ ⁻ propagation delay		6.0V	$C_L=50\text{pF}$		-	-	45	ns
		2.0V	$C_L=50\text{pF}$	see Figure 3	-	-	265	ns
nR ⁻ tonQ ⁻ 、nQ propagation delay		4.5V	$C_L=50\text{pF}$		-	-	53	ns
		6.0V	$C_L=50\text{pF}$		-	-	45	ns
nS tonQ ⁻ 、nQ		2.0V	$C_L=50\text{pF}$	see Figure 4	-	-	270	ns
		4.5V	$C_L=50\text{pF}$		-	-	54	ns
nS tonQ ⁻ 、nQ		6.0V	$C_L=50\text{pF}$		-	-	46	ns
		2.0V	$C_L=50\text{pF}$	see Figure 4	-	-	235	ns



propagation delay		4.5V	C _L =50pF		-	-	47	ns
		6.0V	C _L =50pF		-	-	40	ns
transition time	t _{THL} , t _{T LH}	2.0V	C _L =50pF	see Figure 3	-	-	110	ns
		4.5V	C _L =50pF		-	-	22	ns
		6.0V	C _L =50pF		-	-	19	ns
nCP ⁻ HIGH or LOW pulse width	tw	2.0V	C _L =50pF	see Figure 3	120	-	-	ns
		4.5V	C _L =50pF		24	-	-	ns
		6.0V	C _L =50pF		20	-	-	ns
nS, nR ⁻ LOW pulse width	tw	2.0V	C _L =50pF	see Figure 4	120	-	-	ns
		4.5V	C _L =50pF		24	-	-	ns
		6.0V	C _L =50pF		20	-	-	ns
nR ⁻ tonCP recovery time	t _{rec}	2.0V	C _L =50pF	see Figure 4	150	-	-	ns
		4.5V	C _L =50pF		30	-	-	ns
		6.0V	C _L =50pF		26	-	-	ns
nS ⁻ tonCP recovery time	t _{rec}	2.0V	C _L =50pF	see Figure 4	120	-	-	ns
		4.5V	C _L =50pF		24	-	-	ns
		6.0V	C _L =50pF		20	-	-	ns
nJ and nK ton CP set-up time	tsu	2.0V	C _L =50pF	see Figure 3	120	-	-	ns
		4.5V	C _L =50pF		24	-	-	ns
		6.0V	C _L =50pF		20	-	-	ns
nJ and nK ton CP hold time	th	2.0V	C _L =50pF	see Figure 3	0	-	-	ns
		4.5V	C _L =50pF		0	-	-	ns
		6.0V	C _L =50pF		0	-	-	ns
maximum frequency	fmax	2.0V	C _L =50pF	see Figure 3	4.0	-	-	MHZ
		4.5V	C _L =50pF		20	-	-	MHZ
		6.0V	C _L =50pF		24	-	-	NHZ

SN74HCT112

nCP ⁻ tonQ propagation delay	t _{PLH} , t _{PHL}	4.5V	C _L =50pF	see Figure 3	-	-	53	ns
nCP ⁻ tonQ ⁻ propagation delay		4.5V	C _L =50pF	see Figure 3	-	-	60	ns
nR ⁻ tonQ ⁻ nQ propagation delay		4.5V	C _L =50pF	see Figure 4	-	-	56	ns
nS ⁻ tonQ ⁻ nQ propagation delay		4.5V	C _L =50pF	see Figure 4	-	-	48	ns
transition time	t _{THL} , t _{T LH}	4.5V	C _L =50pF	see Figure 3	-	-	22	ns
nCP ⁻ HIGH or LOW pulse width	tw	4.5V	C _L =50pF	see Figure 3	24	-	-	ns
nS, nR ⁻ LOW pulse width		4.5V	C _L =50pF	see Figure 4	27	-	-	ns
nR ⁻ tonCP recovery time	t _{rec}	4.5V	C _L =50pF	see Figure 4	30	-	-	ns



nS tonCP recovery time		4.5V	C _L =50pF	see Figure 4	30	-	-	ns
nJ and nK ton CP set-up time	tsu	4.5V	C _L =50pF	see Figure 3	24	-	-	ns
nJ and nK ton CP hold time	th	4.5V	C _L =50pF	see Figure 3	0	-	-	ns
maximum frequency	fmax	4.5V	C _L =50pF	see Figure 3	20	-	-	MHZ

Testing Circuit

AC Testing Circuit

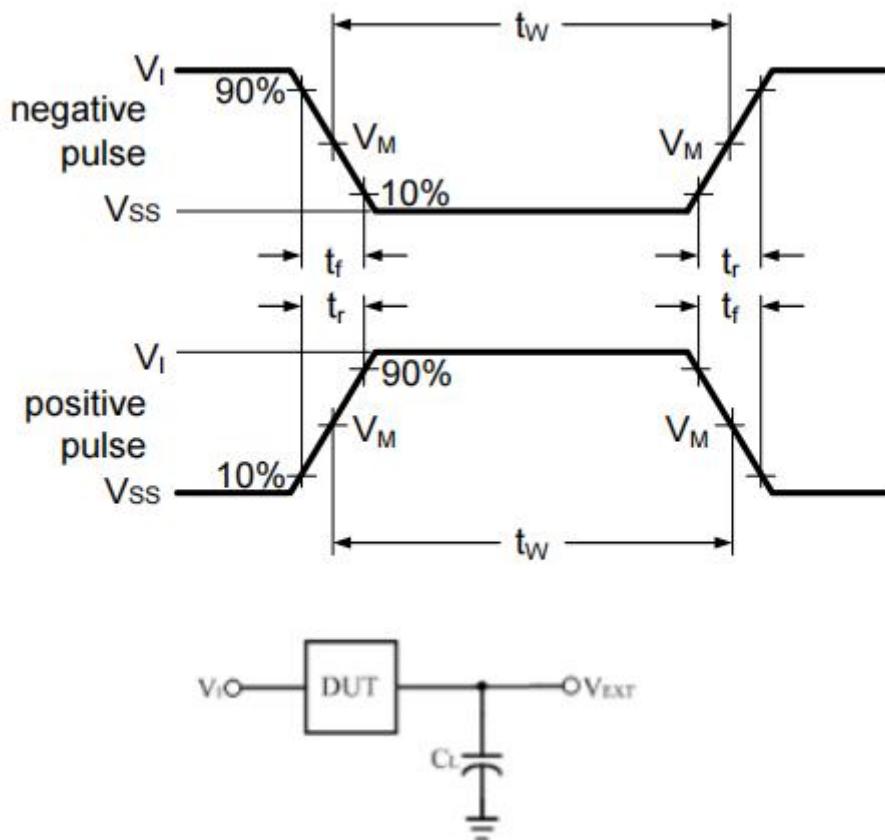


Figure 2 Load circuit
 C_L includes probe and jig capacitance.

AC Testing Waveforms

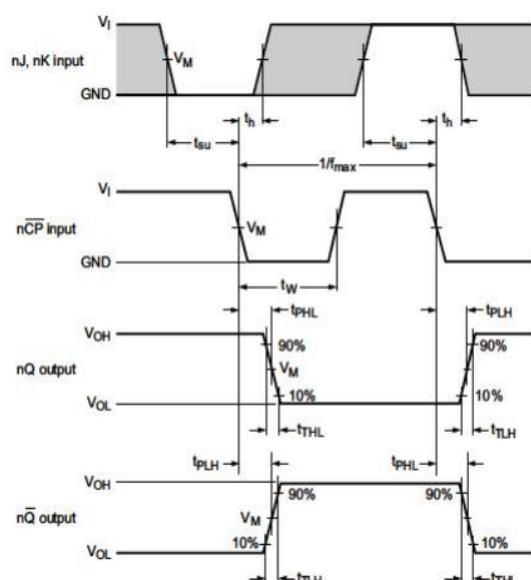


Figure 3 Clock propagation delays, output transition time, pulse width, set-up, hold times, and maximum frequency

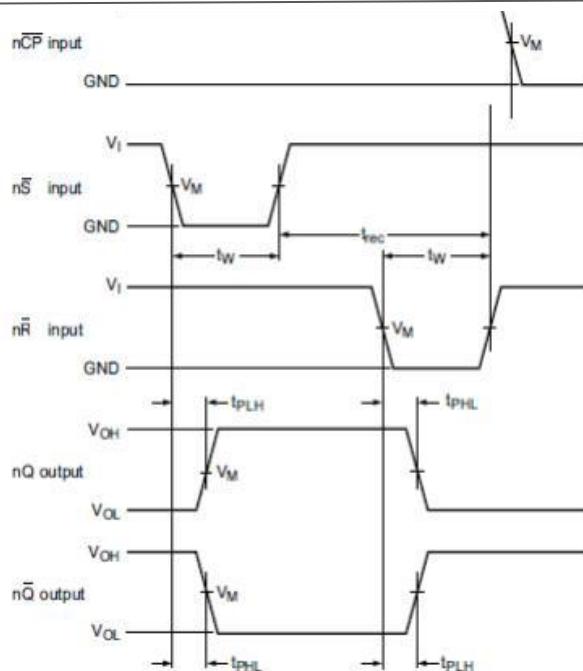


Figure 4 Set and reset propagation delays, pulse widths and recovery time

Measurement Points

Type	Input		Output		
	V_M	V_M	V_X	V_Y	
SN74HC112	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$0.1 \times V_{CC}$	$0.9 \times V_{CC}$	
SN74HCT112	1.3V	1.3V	$0.1 \times V_{CC}$	$0.9 \times V_{CC}$	

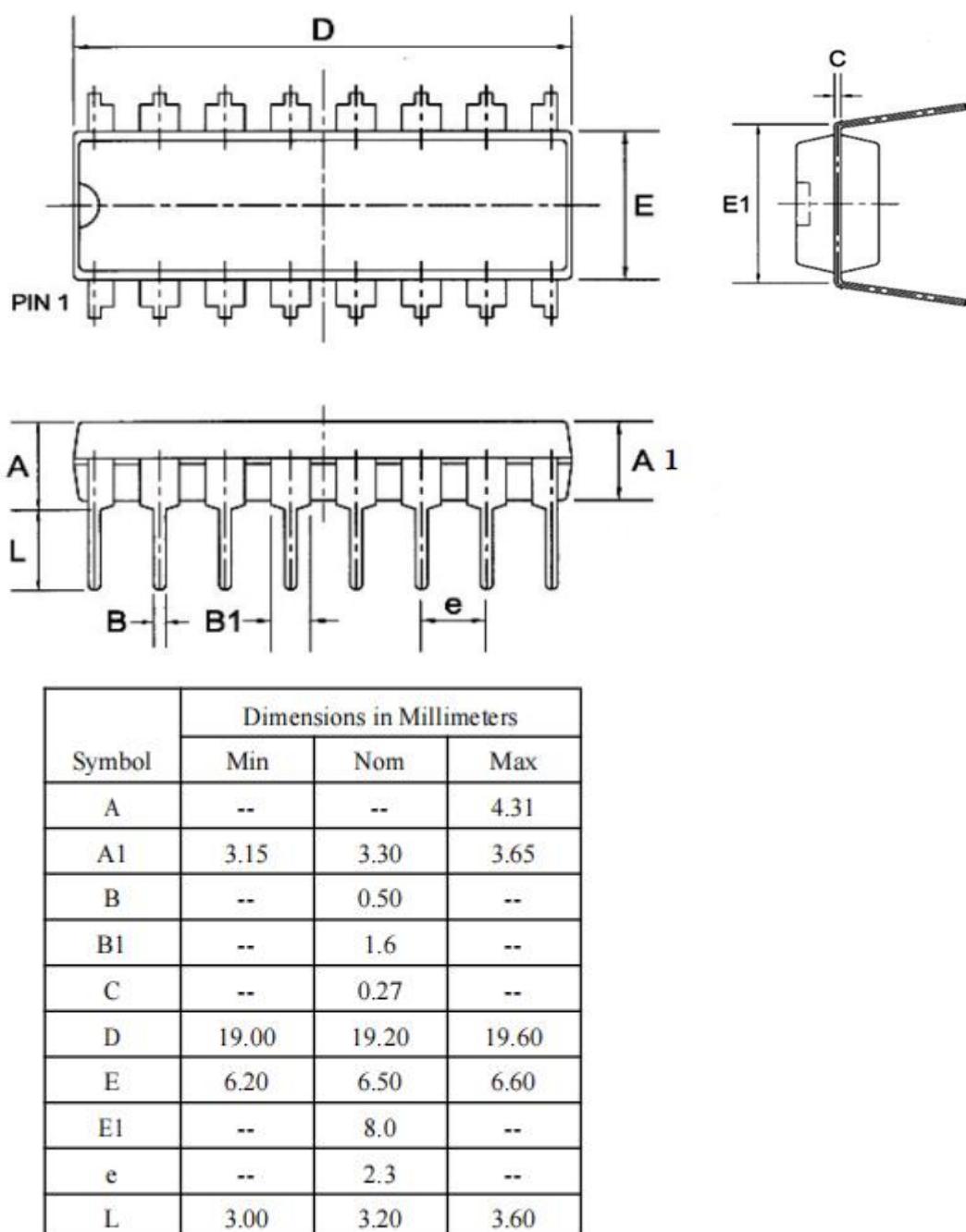
Test Data

Type	Input		C_L	V_{EXT}		
	V_I	$t_r = t_f$		t_{PLH}/t_{PHL}	t_{PLZ}/t_{PZL}	t_{PHZ}/t_{PZH}
SN74HC112	V_{CC}	6.0ns	50pF	Open	V_{CC}	GND
SN74HCT112	3.0V	6.0ns	50pF	Open	V_{CC}	GND



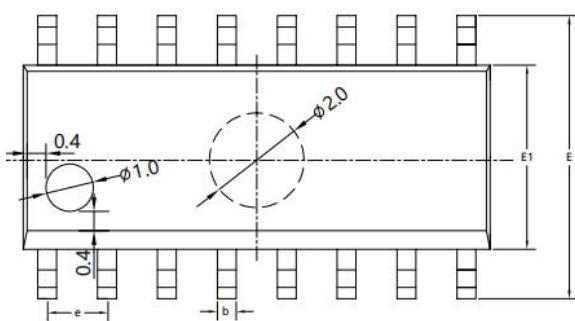
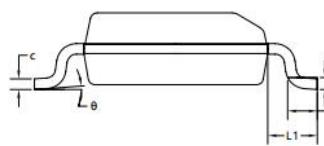
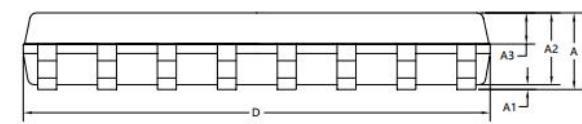
Package Information

DIP16



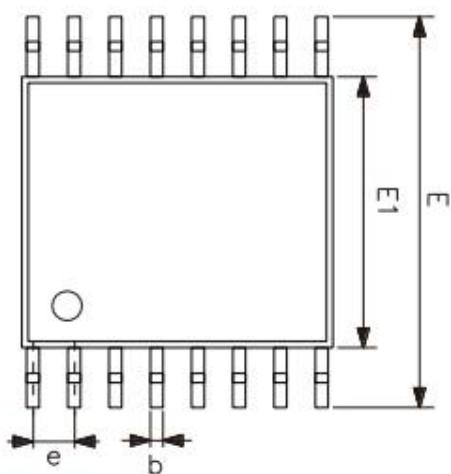
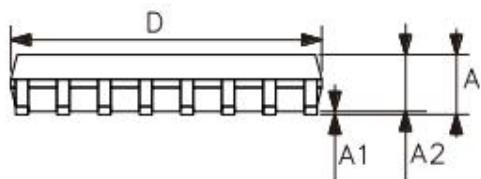


SOP16



SYMBOL	MILIMETER		
	MIN	NOM	MAX
A	1.50	1.60	1.70
A1	0.10	0.15	0.25
A2	1.40	1.45	1.50
A3	0.60	0.65	0.70
b	0.30	0.40	0.50
c	0.15	0.20	0.25
D	9.80	9.90	10.00
E	5.80	6.00	6.20
E1	3.85	3.90	3.95
e	1.27BSC		
L	0.50	0.60	0.70
L1	1.05BSC		
θ	0°	4°	8°

TSSOP16



Symbol	Dimensions (mm)	
	Min.	Max.
A	-	1.20
A1	0.05	0.15
A2	0.80	1.05
b	0.19	0.30
c	0.09	0.20
D	4.90	5.10
E1	4.30	4.50
E	6.20	6.60
e	0.65	
L	0.45	0.75
θ	0°	8°



Statement:

- ✧ Shenzhen xinbole electronics co., ltd. reserves the right to change the product specifications, without notice! Before placing an order, the customer needs to confirm whether the information obtained is the latest version, and verify the integrity of the relevant information.
- ✧ Any semiconductor product is liable to fail or malfunction under certain conditions, and the buyer shall be responsible for complying with safety standards in the system design and whole machine manufacturing using Shenzhen xinbole electronics co., ltd products, and take appropriate security measures to avoid the potential risk of failure may result in personal injury or property losses of the situation occurred!
- ✧ This document is for referenceonly, and the actual use should be based on the application test results.
- ✧ Product performance is never ending, Shenzhen xinbole electronics co., ltd will be dedicated to provide customers with better performance, better quality of integrated circuit products.